# **Digital Transistors (BRT) R1 = 2.2 k\Omega, R2 = 47 k\Omega**

# NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ )

| Rating                         | Symbol               | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage         | V <sub>CBO</sub>     | 50  | Vdc  |
| Collector-Emitter Voltage      | V <sub>CEO</sub>     | 50  | Vdc  |
| Collector Current – Continuous | Ι <sub>C</sub>       | 100 | mAdc |
| Input Forward Voltage          | V <sub>IN(fwd)</sub> | 12  | Vdc  |
| Input Reverse Voltage          | V <sub>IN(rev)</sub> | 5   | Vdc  |

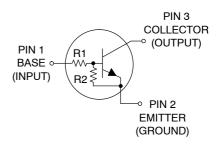
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



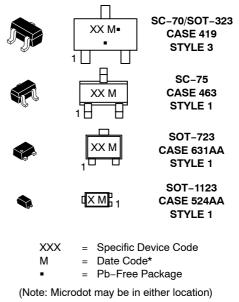
# **ON Semiconductor®**

http://onsemi.com

### **PIN CONNECTIONS**



## MARKING DIAGRAMS



\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

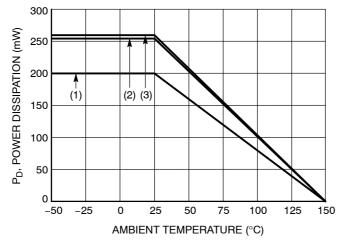
See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.



#### Table 1. ORDERING INFORMATION

| Device                  | Part Marking | Package       | Shipping <sup>†</sup> |
|-------------------------|--------------|---------------|-----------------------|
| MUN5235T1G, SMUN5235T1G | 8M           | SC-70/SOT-323 | 3,000 / Tape & Reel   |
| DTC123JET1G             | 8M           | SC-75         | 3,000 / Tape & Reel   |
| DTC123JM3T5G            | 8M           | SOT-723       | 8,000 / Tape & Reel   |
| NSBC123JF3T5G           | V            | SOT-1123      | 8,000 / Tape & Reel   |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



SC-75 and SC-70/SOT-323; Minimum Pad
 SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace
 SOT-723; Minimum Pad

### Figure 1. Derating Curve

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### **Table 2. THERMAL CHARACTERISTICS**

| Characteristic  |  | Symbol                            | Max                      | Unit        |
|---|--|-----------------------------------|--------------------------|-------------|
| THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5235)                             |  |                                   |                          | •           |
| Total Device Dissipation<br>$T_A = 25^{\circ}C$<br>Derate above 25°C          | (Note 1)<br>(Note 2)<br>(Note 1)<br>(Note 2) | P <sub>D</sub>                    | 202<br>310<br>1.6<br>2.5 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                                    | (Note 1)<br>(Note 2)                         | $R_{\thetaJA}$                    | 618<br>403               | °C/W        |
| Thermal Resistance,<br>Junction to Lead                                       | (Note 1)<br>(Note 2)                         | $R_{	extsf{	heta}JL}$             | 280<br>332               | °C/W        |
| Junction and Storage Temperature Range  |  | T <sub>J</sub> , T <sub>stg</sub> | –55 to +150              | °C          |
| Thermal Characteristics (SC-75) (DTC123JE)                                    |  |                                   |                          | •           |
| Total Device Dissipation<br>$T_A = 25^{\circ}C$<br>Derate above $25^{\circ}C$ | (Note 1)<br>(Note 2)<br>(Note 1)<br>(Note 2) | P <sub>D</sub>                    | 200<br>300<br>1.6<br>2.4 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                                    | (Note 1)<br>(Note 2)                         | $R_{\thetaJA}$                    | 600<br>400               | °C/W        |
| Junction and Storage Temperature Range  |  | T <sub>J</sub> , T <sub>stg</sub> | –55 to +150              | °C          |
| Thermal Characteristics (SOT-723) (DTC123JM3)                                 |  |                                   |                          |             |
| Total Device Dissipation<br>$T_A = 25^{\circ}C$<br>Derate above $25^{\circ}C$ | (Note 1)<br>(Note 2)<br>(Note 1)<br>(Note 2) | P <sub>D</sub>                    | 260<br>600<br>2.0<br>4.8 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                                    | (Note 1)<br>(Note 2)                         | $R_{\thetaJA}$                    | 480<br>205               | °C/W        |
| Junction and Storage Temperature Range  |  | T <sub>J</sub> , T <sub>stg</sub> | –55 to +150              | °C          |
| Thermal Characteristics (SOT-1123) (NSBC123JF3)                               |  |                                   |                          |             |
| Total Device Dissipation<br>$T_A = 25^{\circ}C$<br>Derate above $25^{\circ}C$ | (Note 3)<br>(Note 4)<br>(Note 3)<br>(Note 4) | P <sub>D</sub>                    | 254<br>29<br>2.0<br>2.4  | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                                    |  | $R_{\thetaJA}$                    | 493<br>421               | °C/W        |
| Thermal Resistance, Junction to Lead  | (Note 3)                                     | $R_{\theta JL}$                   | 193                      | °C/W        |
| Junction and Storage Temperature Range  |  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150              | °C          |

FR-4 @ Minimum Pad.
 FR-4 @ 1.0 x 1.0 Inch Pad.
 FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

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| Characteristic  | Symbol                         | Min   | Тур   | Max   | Unit |  |
|---|--------------------------------|-------|-------|-------|------|--|
| OFF CHARACTERISTICS   |                                |       |       |       |      |  |
| Collector–Base Cutoff Current $(V_{CB} = 50 \text{ V}, I_E = 0)$  | I <sub>CBO</sub>               | -     | -     | 100   | nAdc |  |
| Collector-Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$   | I <sub>CEO</sub>               | -     | _     | 500   | nAdc |  |
| Emitter-Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}, I_C = 0$ )   | I <sub>EBO</sub>               | _     | _     | 0.2   | mAdc |  |
| Collector–Base Breakdown Voltage $(I_C = 10 \ \mu A, I_E = 0)$  | V <sub>(BR)CBO</sub>           | 50    | _     | -     | Vdc  |  |
| Collector-Emitter Breakdown Voltage (Note 5) $(I_C = 2.0 \text{ mA}, I_B = 0)$  | V <sub>(BR)</sub> CEO          | 50    | _     | -     | Vdc  |  |
| ON CHARACTERISTICS  |                                | -     | -     |       | -    |  |
| DC Current Gain (Note 5)<br>( $I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$ )   | h <sub>FE</sub>                | 80    | 140   | -     |      |  |
| Collector – Emitter Saturation Voltage (Note 5) $(I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA})$                                     | V <sub>CE(sat)</sub>           | -     | _     | 0.25  | Vdc  |  |
| Input Voltage (off) (V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 100 $\mu$ A)   | V <sub>i(off)</sub>            | -     | 0.6   | -     | Vdc  |  |
| Input Voltage (on) $(V_{CE} = 0.2 \text{ V}, I_C = 5.0 \text{ mA})$   | V <sub>i(on)</sub>             | -     | 0.8   | _     | Vdc  |  |
| Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )                           | V <sub>OL</sub>                | -     | _     | 0.2   | Vdc  |  |
| Output Voltage (off) $(V_{CC} = 5.0 \text{ V}, \text{ V}_{\text{B}} = 0.5 \text{ V}, \text{ R}_{\text{L}} = 1.0 \text{ k}\Omega)$ | V <sub>OH</sub>                | 4.9   | _     | _     | Vdc  |  |
| Input Resistor  | R1                             | 1.5   | 2.2   | 2.9   | kΩ   |  |
| Resistor Ratio  | R <sub>1</sub> /R <sub>2</sub> | 0.038 | 0.047 | 0.056 |      |  |

5. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq$  2%.

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TYPICAL CHARACTERISTICS MUN5235, DTC123JE, DTC123JM3

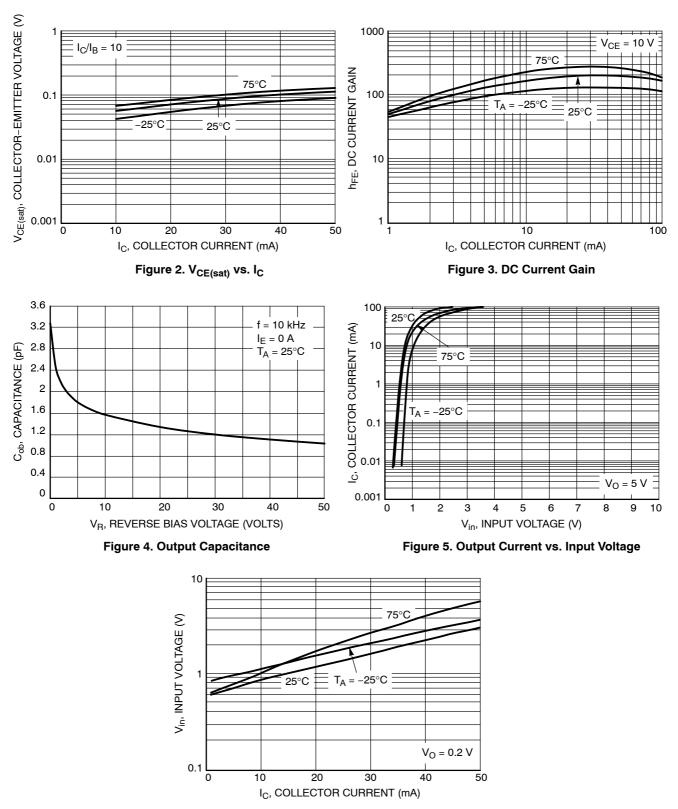
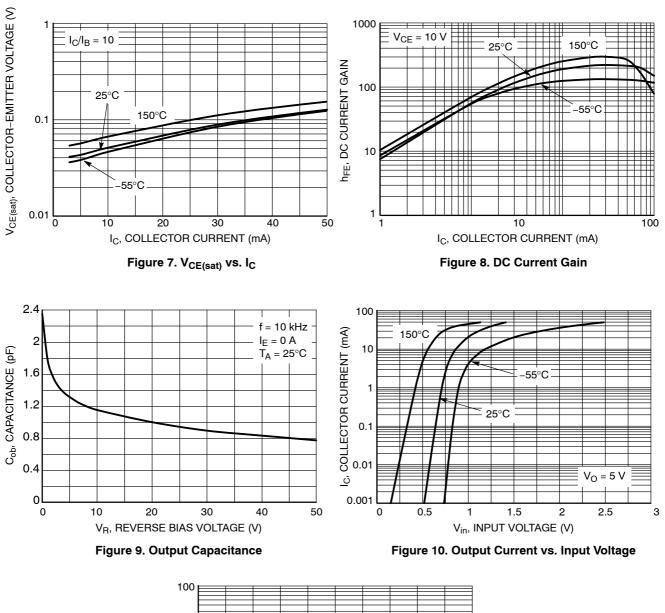


Figure 6. Input Voltage vs. Output Current

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TYPICAL CHARACTERISTICS NSBC123JF3



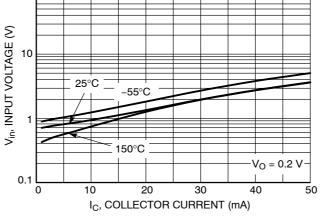
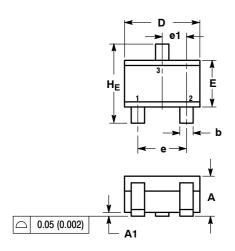


Figure 11. Input Voltage vs. Output Current

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# PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 **ISSUE N** 



A2

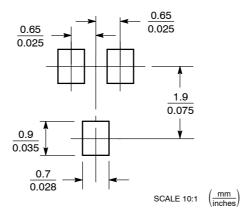
NOTES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.

|     | MILLIMETERS |          |      | INCHES    |           |       |
|-----|-------------|----------|------|-----------|-----------|-------|
| DIM | MIN         | NOM      | MAX  | MIN       | NOM       | MAX   |
| Α   | 0.80        | 0.90     | 1.00 | 0.032     | 0.035     | 0.040 |
| A1  | 0.00        | 0.05     | 0.10 | 0.000     | 0.002     | 0.004 |
| A2  | 0.70 REF    |          |      |           | 0.028 REF | -     |
| b   | 0.30        | 0.35     | 0.40 | 0.012     | 0.014     | 0.016 |
| c   | 0.10        | 0.18     | 0.25 | 0.004     | 0.007     | 0.010 |
| D   | 1.80        | 2.10     | 2.20 | 0.071     | 0.083     | 0.087 |
| Е   | 1.15        | 1.24     | 1.35 | 0.045     | 0.049     | 0.053 |
| е   | 1.20        | 1.30     | 1.40 | 0.047     | 0.051     | 0.055 |
| e1  |             | 0.65 BSC |      | 0.026 BSC |           |       |
| L   | 0.20        | 0.38     | 0.56 | 0.008     | 0.015     | 0.022 |
| HE  | 2.00        | 2.10     | 2.40 | 0.079     | 0.083     | 0.095 |



STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR

**SOLDERING FOOTPRINT\*** 

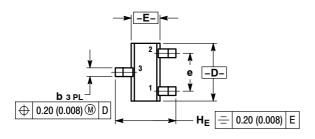


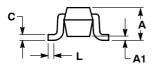
\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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## PACKAGE DIMENSIONS

SC-75/SOT-416 **CASE 463 ISSUE F** 





NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

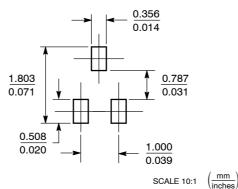
2. CONTROLLING DIMENSION: MILLIMETER.

|     | MILLIMETERS |      |      | INCHES   |       |       |
|-----|-------------|------|------|----------|-------|-------|
| DIM | MIN         | NOM  | MAX  | MIN      | NOM   | MAX   |
| Α   | 0.70        | 0.80 | 0.90 | 0.027    | 0.031 | 0.035 |
| A1  | 0.00        | 0.05 | 0.10 | 0.000    | 0.002 | 0.004 |
| b   | 0.15        | 0.20 | 0.30 | 0.006    | 0.008 | 0.012 |
| С   | 0.10        | 0.15 | 0.25 | 0.004    | 0.006 | 0.010 |
| D   | 1.55        | 1.60 | 1.65 | 0.059    | 0.063 | 0.067 |
| E   | 0.70        | 0.80 | 0.90 | 0.027    | 0.031 | 0.035 |
| е   | 1.00 BSC    |      |      | 0.04 BSC |       |       |
| L   | 0.10        | 0.15 | 0.20 | 0.004    | 0.006 | 0.008 |
| HE  | 1.50        | 1.60 | 1.70 | 0.061    | 0.063 | 0.065 |



STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

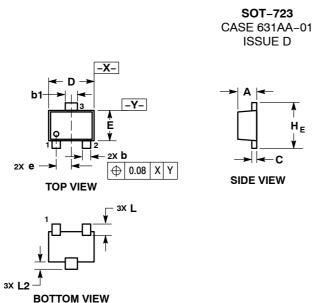
**SOLDERING FOOTPRINT\*** 



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

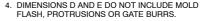
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### PACKAGE DIMENSIONS



NOTES:

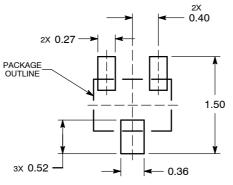
- NOTES:
  DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.



|          | MILLIMETERS |      |      |  |  |
|----------|-------------|------|------|--|--|
| DIM      | MIN NOM MAX |      |      |  |  |
| Α        | 0.45        | 0.50 | 0.55 |  |  |
| b        | 0.15        | 0.21 | 0.27 |  |  |
| b1       | 0.25        | 0.31 | 0.37 |  |  |
| С        | 0.07        | 0.12 | 0.17 |  |  |
| D        | 1.15        | 1.20 | 1.25 |  |  |
| Е        | 0.75        | 0.80 | 0.85 |  |  |
| е        | 0.40 BSC    |      |      |  |  |
| ΗE       | 1.15        | 1.20 | 1.25 |  |  |
| L        | 0.29 REF    |      |      |  |  |
| L2       | 0.15        | 0.20 | 0.25 |  |  |
| STYLE 1: |             |      |      |  |  |

PIN 1. BASE 2. EMITTER 3. COLLECTOR

#### RECOMMENDED **SOLDERING FOOTPRINT\***

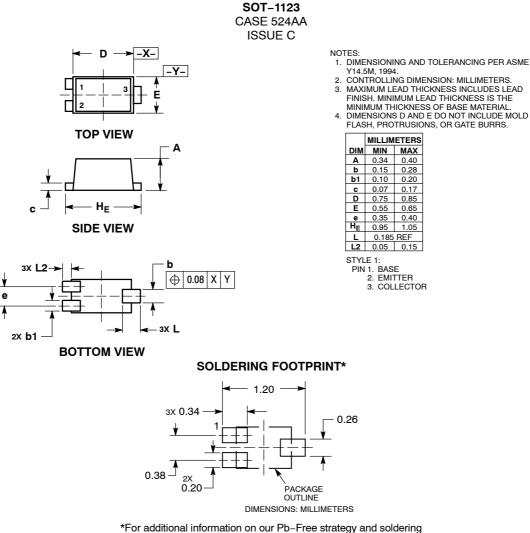


DIMENSIONS: MILLIMETERS

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